

# IPP084N06L3GXKSA1

### IPP084N06L3GXKSA1 Information

www.heiseper.com	 IPP084N06L3GXKSA1 Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 60V 50A TO-220-3 TO-220-3 For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote



Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



# IPP084N06L3GXKSA1 Specifications

Manufacturer Part Number	IPP084N06L3GXKSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	50A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.2V @ 34µA
Gate Charge (Qg) (Max) @ Vgs	29nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	4900pF @ 30V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	79W (Tc)
Rds On (Max) @ Id, Vgs	8.4 mOhm @ 50A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO-220-3
Package / Case	TO-220-3
	Report errors?

#### IPP084N06L3GXKSA1 Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

#### IPP084N06L3GXKSA1 Payment Methods



## IPP084N06L3GXKSA1 Shipping Methods



If you have any question about IPP084N06L3GXKSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com